

	Class	Subclass
ISSUE CLASSIFICATION		

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PATENT NUMBER

U.S. UTILITY Patent Application

O.I.P.E.

PATENT DATE

SCANNED

M2 Q.A. 652

APPLICATION NO. 09/842631	CONT/PRIOR F	CLASS 257	SUBCLASS 295	ART UNIT 2815	EXAMINER Diam
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APPLICANTS

Wendong Zhen ..

THE

Semiconductor device having ferroelectric thin film and fabricating method therefor

PTO-2040
12/89

ISSUING CLASSIFICATION

[illegible]

<input type="checkbox"/> TERMINAL DISCLAIMER	DRAWINGS			CLAIMS ALLOWED	
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.
<input type="checkbox"/> The term of this patent subsequent to _____ (date) has been disclaimed. <input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S Patent. No. _____ _____ _____	_____ (Assistant Examiner) _____ (Date)			NOTICE OF ALLOWANCE MAILED	
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